

# 16-Channel, 12-/16-Bit *nano*DAC+ with 2 ppm/°C Voltage Reference TC, I<sup>2</sup>C Interface

**Data Sheet** 

AD5673R/AD5677R

### **FEATURES**

**High performance** 

High relative accuracy (INL): ±4 LSB maximum at 16 bits

(AD5677R only)

TUE: ±0.14% of FSR maximum

Offset error: ±1.5 mV maximum

Gain error: ±0.06% of FSR maximum

Low drift, 2.5 V voltage reference TC: 2 ppm/°C typical

40 mA short-circuit current

Wide operating ranges

-40°C to +125°C temperature range

2.7 V to 5.5 V power supply range

Simplified implementation

User selectable gain of 1 or 2 (GAIN pin)

1.8 V logic compatibility

400 kHz I<sup>2</sup>C-compatible serial interface

28-lead, 4 mm  $\times$  4 mm, RoHS compliant LFCSP

### **APPLICATIONS**

Optical transceivers
Base station power amplifiers
Process control (programmable logic controller (PLC)
input/output cards)
Industrial automation
Data acquisition systems

### **GENERAL DESCRIPTION**

The AD5673R/AD5677R are low power, 16-channel, 12-/16-bit, buffered voltage output, digital-to-analog converters (DACs) that include a 2.5 V, 2 ppm/°C internal reference (enabled by default), and a gain select pin, resulting in a full-scale output of 2.5 V (gain = 1) or 5 V (gain = 2). The devices operate from a single, 2.7 V to 5.5 V supply range and are guaranteed monotonic by design. The AD5673R/AD5677R are available in a 28-lead lead frame chip scale package (LFCSP) and incorporate a power-on reset (POR) circuit that ensures that the DAC outputs power up to and remain at zero scale or midscale until a valid write. The AD5673R/AD5677R contain a power-down mode that reduces the current consumption to 2  $\mu$ A typical.

Table 1. Octal and 16-Channel nanoDAC+® Devices

Channel Count	Interface	Reference	16-Bit	12-Bit
8	SPI	Internal	AD5676R	AD5672R
		External	AD5676	Not applicable
	I <sup>2</sup> C	Internal	AD5675R	AD5671R
16	SPI	Internal	AD5679R	AD5674R
		External	AD5679	AD5674
	I <sup>2</sup> C	Internal	AD5677R	AD5673R

### **PRODUCT HIGHLIGHTS**

- High channel density: 16 channels in 4 mm  $\times$  4 mm LFCSP.
- 2. High relative accuracy (INL). AD5673R (12-bit): ±1 LSB maximum. AD5677R (16-bit): ±4 LSB maximum.
- 3. Low drift, 2.5 V, on-chip reference.

# AD5673R/AD5677R SCL REGISTER REGISTER DAC REGISTER REGISTER DAC STRING DAC A1 A1 A1 A2 INPUT REGISTER REGISTER DAC REGISTER REGISTER DAC REGISTER REGISTER DAC REGISTER REGISTER DAC REGISTER REGISTER REGISTER DAC REGISTER REG

**FUNCTIONAL BLOCK DIAGRAM** 

Figure 1.

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### **REVISION HISTORY**

4/2020—Revision 0: Initial Version

# SPECIFICATIONS AD5673R SPECIFICATIONS

VDD pin voltage ( $V_{DD}$ ) = 2.7 V to 5.5 V, 1.62 V  $\leq$  VLOGIC pin voltage ( $V_{LOGIC}$ )  $\leq$  5.5 V, load resistance ( $R_L$ ) = 2 k $\Omega$ , load capacitance ( $C_L$ ) = 200 pF, all specifications are  $T_J$  =  $-40^{\circ}$ C to +125°C, typical at  $T_A$  = 25°C, unless otherwise noted.

Table 2.

Parameter	Min	Тур	Max	Unit	Test Conditions/Comments
STATIC PERFORMANCE <sup>1</sup>					
Resolution	12			Bits	
Relative Accuracy, Integral Nonlinearity (INL)		±0.12	±1	LSB	Gain = 1
		±0.12	±1	LSB	Gain = 2
Differential Nonlinearity (DNL)		±0.05	±0.1	LSB	Gain = 1
		±0.05	±0.1	LSB	Gain = 2
Zero Code Error		8.0	1.6	mV	Gain = 1 or gain = 2
Offset Error		-0.75	±2	mV	Gain = 1
		-0.1	±1.5	mV	Gain = 2
Full-Scale Error		-0.018	±0.14	% of FSR	Gain = 1
		-0.013	±0.07	% of FSR	Gain = 2, $V_{DD}$ = 5.5 V
Gain Error		+0.04	±0.12	% of FSR	Gain = 1
		-0.02	±0.06	% of FSR	Gain = 2
Total Unadjusted Error (TUE)		±0.03	±0.18	% of FSR	Gain = 1
		±0.006	±0.14	% of FSR	Gain = 2
Offset Error Drift		±2		μV/°C	Gain = 1
DC Power Supply Rejection Ratio (PSRR)		0.25		mV/V	DAC code = midscale, $V_{DD} = 5 \text{ V} \pm 10\%$
DC Crosstalk		±2		μV	Due to single channel, full-scale output change, internal reference, gain = 1
		±3		μV/mA	Due to load current change, external reference, gain = 2
		±2		μV	Due to powering down (per channel), internal reference, gain = 1
OUTPUT CHARACTERISTICS					
Output Power-Up Voltage		0		V	Gain = 1, AD5673R-1
		0		V	Gain = 2, AD5673R-1
		1.25		V	Gain = 1, AD5673R-2
		2.5		V	Gain = 2, AD5673R-2
Output Voltage Range	0		2.5	V	Gain = 1
	0		5	V	Gain = 2
Capacitive Load Stability		2		nF	R <sub>L</sub> = ∞
		10		nF	$R_L = 1 \text{ k}\Omega$
Load Regulation		183		μV/mA	$V_{DD} = 5 \text{ V} \pm 10\%$ , DAC code = midscale, -30 mA \le output current ( $I_{OUT}$ ) \le +30 mA
		177		μV/mA	$V_{DD} = 3 V \pm 10\%$ , DAC code = midscale, -20 mA $\leq$ $I_{OUT} \leq +20$ mA
Short-Circuit Current <sup>2</sup>		40		mA	
Load Impedance at Rails <sup>3</sup>		25		Ω	
Power-Up Time		3		μs	Exiting power-down mode, V <sub>DD</sub> = 5 V
REFERENCE INPUT					-
Reference Input Current		0.8		mA	Reference voltage $(V_{REF}) = V_{DD} = V_{LOGIC} = 5.5 V$ , gain = 1
		1.6		mA	$V_{REF} = V_{DD} = V_{LOGIC} = 5.5 \text{ V}, \text{ gain} = 2$
Reference Input Range	1	-	$V_{DD}$	V	Gain = 1
, , ,	1		$V_{DD}/2$	V	Gain = 2
Reference Input Impedance		7		kΩ	Gain = 1
h		3.5		kΩ	Gain = 2

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Parameter	Min	Тур	Max	Unit	Test Conditions/Comments
REFERENCE OUTPUT					
Output Voltage⁴	2.4975		2.5025	٧	
Voltage Reference Temperature Coefficient (TC) <sup>5,6</sup>		2	5	ppm/°C	See voltage reference temperature coefficient (TC) in the Terminology section
Output Impedance		0.04		Ω	
Output Voltage Noise		13		μV p-p	0.1 Hz to 10 Hz
Output Voltage Noise Density		240		nV/√Hz	At ambient temperature $(T_A)$ , $f = 10$ kHz, $C_L = 10$ nF, gain = 1 or 2
Load Regulation Sourcing		29		μV/mA	At T <sub>A</sub>
Load Regulation Sinking		74		μV/mA	At T <sub>A</sub>
Output Current Load Capability		±20		mA	$V_{DD} \ge 3 V$
Line Regulation		43		μV/V	At T <sub>A</sub>
Long-Term Stability Drift		77		ppm	After 1000 hours at 25°C
Thermal Hysteresis		125		ppm	First cycle
		25		ppm	Additional cycles
LOGIC INPUTS					
Input Current			±1	μΑ	Per pin
Input Voltage					
Low, V <sub>IL</sub>			$0.3 \times V_{\text{LOGIC}}$	V	$1.62 \text{ V} \leq \text{V}_{\text{LOGIC}} \leq 3.3 \text{ V}$
			$0.25 \times V_{LOGIC}$	٧	$3.3 \text{ V} \leq \text{V}_{\text{LOGIC}} \leq 5.5 \text{ V}$
High, V <sub>IH</sub>	$0.7 \times V_{LOGIC}$			V	
Pin Capacitance		4		pF	
LOGIC OUTPUTS (SDA)					
Output Voltage					
Low, V <sub>OL</sub>			0.4	V	Output low current $(I_{OL}) = 3 \text{ mA}$
High, V <sub>OH</sub>	$V_{\text{LOGIC}} - 0.4$			V	Output high current ( $I_{OH}$ ) = $-3$ mA
Floating State Output Capacitance		9		pF	
POWER REQUIREMENTS					
$V_{LOGIC}$	1.62		5.5	V	1.8 V logic compatibility
V <sub>LOGIC</sub> Supply Current (I <sub>LOGIC</sub> )			3	μΑ	Power-on, -40°C to +105°C
			3	μΑ	Power-on, -40°C to +125°C
			3	μΑ	Power-down, –40°C to +105°C
			3	μΑ	Power-down, –40°C to +125°C
$V_{DD}$	2.7		5.5	V	Gain = 1
	$V_{REF} + 1.5$		5.5	٧	Gain = 2
V <sub>DD</sub> Supply Current (I <sub>DD</sub> )					$V_{IH} = V_{DD}$ , $V_{IL} = GND$ , $V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}$
Normal Mode <sup>7</sup>		2.3	2.53	mA	Internal reference off, –40°C to +85°C
		3.4	3.8	mA	Internal reference on, –40°C to +85°C
		2.3	2.6	mA	Internal reference off
		3.4	4.2	mA	Internal reference on
All Power-Down Modes <sup>8</sup>		2	3.4	μΑ	Power-down to 1 kΩ, –40°C to +85°C
		2	5	μΑ	Power-down to 1 kΩ, –40°C to +105°C
		2	11	μA	Power-down to 1 kΩ, –40°C to +125°C

<sup>&</sup>lt;sup>1</sup> DC specifications tested with the outputs unloaded, unless otherwise noted. Upper dead band = 10 mV and exists only when  $V_{REF} = V_{DD}$  with gain = 1, or when  $V_{REF}/2 = V_{DD}$  with gain = 2. Linearity calculated using a reduced code range of 12 to 4080.

 $^{5}$  Reference is trimmed and tested at two temperatures and is characterized from  $-40^{\circ}$ C to  $+125^{\circ}$ C.

<sup>&</sup>lt;sup>2</sup> V<sub>DD</sub> = 5 V. The device includes current limiting intended to protect the devices during temporary overload conditions. Junction temperature (T<sub>J</sub>) can be exceeded during current limit. Operation above the specified maximum operation junction temperature can impair device reliability.

 $<sup>^3</sup>$  When drawing a load current at either rail, the output voltage headroom with respect to that rail is limited by the 25  $\Omega$  typical channel resistance of the output devices. For example, when sinking 1 mA, the minimum output voltage = 25  $\Omega$  × 1 mA = 25 mV.

<sup>4</sup> Initial accuracy presolder reflow is ±750 µV. Output voltage includes the effects of preconditioning drift. See the Internal Reference Setup section.

<sup>&</sup>lt;sup>6</sup> Voltage reference temperature coefficient is calculated as per the box method. See the voltage reference temperature coefficient (TC) definition in the Terminology section for further information.

<sup>&</sup>lt;sup>7</sup> Interface inactive. All DACs active. DAC outputs unloaded.

<sup>&</sup>lt;sup>8</sup> All DACs powered down.

### **AD5677R SPECIFICATIONS**

 $V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}, 1.62 \text{ V} \le V_{LOGIC} \le 5.5 \text{ V}, R_L = 2 \text{ k}\Omega, C_L = 200 \text{ pF}, all specifications are } T_J = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}, \text{ typical at } T_A = 25 ^{\circ}\text{C}, \text{ unless otherwise noted.}$ 

Table 3.

Parameter	Min	Тур	Max	Unit	Test Conditions/Comments
STATIC PERFORMANCE <sup>1</sup>					
Resolution	16			Bits	
INL		±1.8	±4	LSB	Gain = 1
		±1.7	±4	LSB	Gain = 2
DNL		±0.7	±1	LSB	Gain = 1
5.12		±0.5	±1	LSB	Gain = 2
Zero Code Error		0.8	1.6	mV	Gain = 1 or gain = 2
Offset Error		-0.75	±2	mV	Gain = 1
onset Enoi		-0.1	±1.5	mV	Gain = 2
Full-Scale Error		-0.018	±0.14	% of FSR	Gain = 1
r dii Scale Eiroi		-0.013	±0.07	% of FSR	Gain = 2, V <sub>DD</sub> = 5.5 V
Gain Error		+0.04	±0.07	% of FSR	Gain = 1
Guill Elloi		-0.02	±0.06	% of FSR	Gain = 2
TUE		±0.03	±0.00	% of FSR	Gain = 1
101		±0.006	±0.18	% of FSR	Gain = 2
Offset Error Drift		±0.000	10.14	μV/°C	Gain = 1
DC PSRR		±2 0.25		μν/ C mV/V	
					DAC code = midscale, V <sub>DD</sub> = 5 V ± 10%
DC Crosstalk		±2		μV	Due to single channel, full-scale output change, internal reference, gain = 1
		±3		μV/mA	Due to load current change, external reference, gain = 2
		±2		μV	Due to powering down (per channel), internal reference,
					gain = 1
OUTPUT CHARACTERISTICS					
Output Power-Up Voltage		0		V	Gain = 1, AD5677R-1
		0		V	Gain = 2, AD5677R-1
		1.25		V	Gain = 1, AD5677R-2
		2.5		V	Gain = 2, AD5677R-2
Output Voltage Range	0		2.5	V	Gain = 1
	0		5	V	Gain = 2
Capacitive Load Stability		2		nF	R <sub>L</sub> = ∞
		10		nF	$R_L = 1 \text{ k}\Omega$
Load Regulation		183		μV/mA	$V_{DD} = 5 \text{ V} \pm 10\%$ , DAC code = midscale, $-30 \text{ mA} \le I_{OUT} \le +30 \text{ mA}$
		177		μV/mA	$V_{DD} = 3 \text{ V} \pm 10\%$ , DAC code = midscale, $-20 \text{ mA} \le I_{OUT} \le +20 \text{ mA}$
Short-Circuit Current <sup>2</sup>		40		mA	
Load Impedance at Rails <sup>3</sup>		25		Ω	
Power-Up Time		3		μs	Exiting power-down mode, $V_{DD} = 5 \text{ V}$
REFERENCE INPUT				pas -	
Reference Input Current		0.8		mA	$V_{REF} = V_{DD} = V_{LOGIC} = 5.5 \text{ V}, \text{ gain} = 1$
nererenee input current		1.6		mA	$V_{REF} = V_{DD} = V_{LOGIC} = 5.5 \text{ V, gain} = 1$ $V_{REF} = V_{DD} = V_{LOGIC} = 5.5 \text{ V, gain} = 2$
Reference Input Range	1	1.0	$V_{DD}$	V	Gain = 1
hererence input hange	1		V <sub>DD</sub> /2	V	Gain = 2
Reference Input Impedance	'	7	<b>V</b> UU <b>/ ∠</b>	kΩ	Gain = 2
nererence input impedance		7 3.5		kΩ	Gain = 1
REFERENCE OUTPUT	-	ر.ي		N3.2	Guiii – 2
	2 4075		2 5025	V	
Output Voltage <sup>4</sup>	2.4975	า	2.5025		See voltage reference temporative coefficient (TC) in the
Voltage Reference TC <sup>5,6</sup>		2	5	ppm/°C	See voltage reference temperature coefficient (TC) in the Terminology section
Output Impedance		0.04		Ω	
Output Voltage Noise		13		μV p-p	0.1 Hz to 10 Hz

Parameter	Min	Тур	Max	Unit	Test Conditions/Comments
Output Voltage Noise Density		240		nV/√Hz	At $T_A$ , $f = 10$ kHz, $C_L = 10$ nF, gain = 1 or 2
Load Regulation Sourcing		29		μV/mA	T <sub>A</sub>
Load Regulation Sinking		74		μV/mA	T <sub>A</sub>
Output Current Load Capability		±20		mA	$V_{DD} \ge 3 \text{ V}$
Line Regulation		43		μV/V	T <sub>A</sub>
Long-Term Stability Drift		77		ppm	After 1000 hours at 25°C
Thermal Hysteresis		125		ppm	First cycle
		25		ppm	Additional cycles
LOGIC INPUTS					
Input Current			±1	μΑ	Per pin
Input Voltage					
Low, V <sub>INL</sub>			$0.3 \times V_{\text{LOGIC}}$	V	$1.62 \text{ V} \leq \text{V}_{\text{LOGIC}} \leq 3.3 \text{ V}$
			$0.25 \times V_{\text{LOGIC}}$	V	$3.3 \text{ V} \leq \text{V}_{\text{LOGIC}} \leq 5.5 \text{ V}$
High, V <sub>INH</sub>	0.7 ×			V	
	V <sub>LOGIC</sub>				
Pin Capacitance		4		pF	
LOGIC OUTPUTS (SDA)					
Output Voltage					
Low, V <sub>OL</sub>			0.4	V	$I_{OL} = 3 \text{ mA}$
High, V <sub>он</sub>	V <sub>LOGIC</sub> – 0.4			V	$I_{OH} = -3 \text{ mA}$
Floating State Output Capacitance		9		pF	
POWER REQUIREMENTS					
$V_{LOGIC}$	1.62		5.5	V	1.8 V logic compatibility
logic			3	μΑ	Power-on, -40°C to +105°C
			3	μΑ	Power-on, -40°C to +125°C
			3	μΑ	Power-down, –40°C to +105°C
			3	μΑ	Power-down, –40°C to +125°C
$V_{DD}$	2.7		5.5	V	Gain = 1
	$V_{REF} + 1.5$		5.5	V	Gain = 2
IDD					$V_{IH} = V_{DD}$ , $V_{IL} = GND$ , $V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}$
Normal Mode <sup>7</sup>		2.3	2.53	mA	Internal reference off, –40°C to +85°C
		3.4	3.8	mA	Internal reference on, –40°C to +85°C
		2.3	2.6	mA	Internal reference off
		3.4	4.2	mA	Internal reference on
All Power-Down Modes <sup>8</sup>		2	3.4	μΑ	Power-down to 1 kΩ, –40°C to +85°C
		2	5	μΑ	Power-down to 1 kΩ, –40°C to +105°C
		2	11	μΑ	Power-down to 1 kΩ, –40°C to +125°C

DC specifications tested with the outputs unloaded, unless otherwise noted. Upper dead band = 10 mV and exists only when VREF = VDD with gain = 1, or when VREF/2 =

V<sub>DD</sub> with gain = 2. Linearity calculated using a reduced code range of 256 to 65,280.

<sup>2</sup>V<sub>DD</sub> = 5 V. The device includes current limiting intended to protect the devices during temporary overload conditions. T<sub>J</sub> can be exceeded during current limit. Operation above the specified maximum operation junction temperature can impair device reliability.

<sup>&</sup>lt;sup>3</sup> When drawing a load current at either rail, the output voltage headroom with respect to that rail is limited by the 25 Ω typical channel resistance of the output

devices. For example, when sinking 1 mA, the minimum output voltage =  $25 \Omega \times 1$  mA = 25 mV.  $^4$  Initial accuracy presolder reflow is  $\pm 750 \,\mu$ V. Output voltage includes the effects of preconditioning drift. See the Internal Reference Setup section.

 $<sup>^{5}</sup>$  Reference is trimmed and tested at two temperatures and is characterized from  $-40^{\circ}$ C to  $+125^{\circ}$ C.

<sup>6</sup> Voltage reference temperature coefficient is calculated as per the box method. See the voltage reference temperature coefficient (TC) definition in the Terminology section for further information.

<sup>&</sup>lt;sup>7</sup> Interface inactive. All DACs active. DAC outputs unloaded.

<sup>&</sup>lt;sup>8</sup> All DACs powered down.

### **AC CHARACTERISTICS**

 $V_{DD} = 2.7 \text{ V to } 5.5 \text{ V}, 1.62 \text{ V} \leq V_{LOGIC} \leq 5.5 \text{ V}, R_L = 2 \text{ k}\Omega \text{ to GND}, C_L = 200 \text{ pF to GND}, all specifications are } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C to } +125 ^{\circ}\text{C to } +125 ^{\circ}\text{C}, \text{ typical } T_J = -40 ^{\circ}\text{C to } +125 ^{\circ}\text{C t$ at  $T_A = 25$ °C, unless otherwise noted.

Table 4.

Parameter	Min	Тур	Max	Unit	Test Conditions/Comments
OUTPUT VOLTAGE SETTLING TIME <sup>1</sup>		6	8	μs	1/4 to 3/4 scale settling to ±2 LSB
SLEW RATE		0.8		V/µs	
DIGITAL-TO-ANALOG GLITCH IMPULSE <sup>1</sup>		1.4		nV-sec	1 LSB change around major carry (internal reference, gain = 1)
DIGITAL FEEDTHROUGH <sup>1</sup>		0.13		nV-sec	
CROSSTALK <sup>1</sup>					
Digital		0.1		nV-sec	
Analog		-0.25		nV-sec	
		-1.3		nV-sec	Internal reference, gain = 2
DAC to DAC		-2.0		nV-sec	Internal reference, gain = 2
TOTAL HARMONIC DISTORTION (THD) <sup>2</sup> -80		-80		dB	At T <sub>A</sub> , bandwidth = 20 kHz, V <sub>DD</sub> = 5 V, output frequency (f <sub>OUT</sub> ) = 1 kHz, internal reference, gain = 2
OUTPUT NOISE SPECTRAL DENSITY (NSD) <sup>1</sup>		300		nV/√Hz	DAC code = midscale, 10 kHz, gain = 2
OUTPUT NOISE		6		μV p-p	0.1 Hz to 10 Hz, gain = 1
SIGNAL-TO-NOISE RATIO (SNR)		90		dB	At $T_A = 25$ °C, bandwidth = 20 kHz, $V_{DD} = 5$ V, $f_{OUT} = 1$ kHz, internal reference
SPURIOUS-FREE DYNAMIC RANGE (SFDR)		83		dB	At $T_A = 25$ °C, bandwidth = 20 kHz, $V_{DD} = 5$ V, $f_{OUT} = 1$ kHz, internal reference
SIGNAL-TO-NOISE-AND-DISTORTION RATIO (SINAD)		80		dB	At $T_A = 25$ °C, bandwidth = 20 kHz, $V_{DD} = 5$ V, $f_{OUT} = 1$ kHz, internal reference, gain = 2

 $<sup>^1</sup>$  See the Terminology section. Measured using internal reference and gain = 1, unless otherwise noted.  $^2$  Digitally generated sine wave ( $f_{OUT}$ ) at 1 kHz.

### **TIMING CHARACTERISTICS**

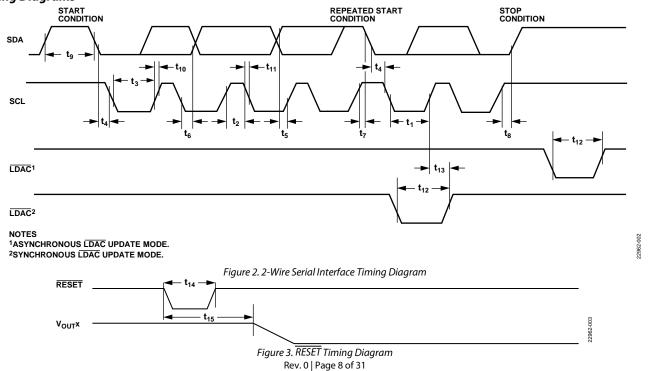
 $V_{DD} = 2.7 \text{ V}$  to 5.5 V, 1.62 V  $\leq V_{LOGIC} \leq$  5.5 V, all specifications are  $T_J = -40 ^{\circ}\text{C}$  to  $+125 ^{\circ}\text{C}$ , unless otherwise noted. See Figure 2 and Figure 3.

Table 5.

Parameter <sup>1</sup>	Min	Тур	Max	Unit	Description
t <sub>1</sub>	2.5			μs	SCL cycle time
$t_2$	0.6			μs	SCL high time
t <sub>3</sub>	1.3			μs	SCL low time
t <sub>4</sub>	0.6			μs	Start or repeated start hold time
<b>t</b> <sub>5</sub>	100			ns	Data setup time
$t_6^2$	0		0.9	μs	Data hold time
t <sub>7</sub>	0.6			μs	Repeated start setup time
t <sub>8</sub>	0.6			μs	Stop condition setup time
t <sub>9</sub>	1.3			μs	Bus free time between a stop condition and a start condition
$t_{10}^{3}$	20 + 0.1C <sub>B</sub>		300	ns	Rise time of SCL and SDA when receiving
t <sub>11</sub> 3,4	20 + 0.1C <sub>B</sub>		300	ns	Fall time of SCL and SDA when transmitting or receiving
t <sub>12</sub>	20			ns	LDAC pulse width
t <sub>13</sub>	400			ns	SCL rising edge to LDAC rising edge
t <sub>14</sub>	8			ns	$\overline{\text{RESET}}$ minimum pulse width low, 1.62 V $\leq$ V <sub>LOGIC</sub> $\leq$ 2.7 V
	10			ns	$\overline{\text{RESET}}$ minimum pulse width low, 2.7 V $\leq$ V <sub>LOGIC</sub> $\leq$ 5.5 V
t <sub>15</sub>	115			ns	$\overline{\text{RESET}}$ activation time, 1.62 V $\leq$ V <sub>LOGIC</sub> $\leq$ 2.7 V
	115			ns	$\overline{\text{RESET}}$ activation time, 2.7 V $\leq$ V <sub>LOGIC</sub> $\leq$ 5.5 V
t <sub>SP</sub> 5	0		50	ns	Pulse width of suppressed spike
$C_B^4$			400	pF	Capacitive load for each bus line
<b>Update Rate</b>			400	kHz	Fast mode
			100	kHz	Standard mode

<sup>&</sup>lt;sup>1</sup> See Figure 2.

### **Timing Diagrams**



<sup>&</sup>lt;sup>2</sup> A master device must provide a hold time of at least 300 ns for the SDA signal (referred to the minimum V<sub>H</sub> of the SCL signal) to bridge the undefined region of the SCL falling edge.

 $<sup>^3</sup>$   $t_{10}$  (rise time) and  $t_{11}$  (fall time) are measured from 0.3  $\times$   $V_{DD}$  to 0.7  $\times$   $V_{DD}.$ 

<sup>&</sup>lt;sup>4</sup>C<sub>B</sub> is the total capacitance of one bus line in pF.

<sup>&</sup>lt;sup>5</sup> Input filtering on the SCL and SDA inputs suppresses noise spikes that are less than 50 ns. Not shown in Figure 2 or Figure 3.

### ABSOLUTE MAXIMUM RATINGS

 $T_A = 25$ °C, unless otherwise noted.

Table 6.

Parameter	Rating
$V_{DD}$ to GND	−0.3 V to +7 V
V <sub>LOGIC</sub> to GND	–0.3 V to +7 V
V <sub>OUT</sub> x <sup>1</sup> to GND	$-0.3  V$ to $V_{DD} + 0.3  V$
V <sub>REF</sub> to GND	$-0.3  V$ to $V_{DD} + 0.3  V$
Digital Input Voltage to GND	$-0.3V$ to $V_{LOGIC}+0.3V$
Operating Junction Temperature Range	−40°C to +125°C
Storage Temperature Range	−65°C to +150°C
Absolute Maximum Junction Temperature	150°C
Reflow Soldering Peak Temperature, Pb Free (J-STD-020)	260°C

<sup>&</sup>lt;sup>1</sup> V<sub>OUT</sub>x is the voltage of the VOUTx pins.

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

### THERMAL RESISTANCE

Thermal performance is directly linked to printed circuit board (PCB) design and operating environment. Careful attention to PCB thermal design is required.

 $\theta_{JA}$  is the natural convection junction to ambient thermal resistance measured in a one cubic foot, sealed enclosure.  $\theta_{JB}$  is the junction to board thermal resistance.  $\theta_{JC}$  is the junction to case thermal resistance.  $\Psi_{JT}$  is the junction to top thermal characterization parameter.  $\Psi_{JB}$  is the junction to board thermal characterization parameter.

**Table 7. Thermal Resistance** 

Package Type <sup>1</sup>	θја	θјβ	ЭгӨ	$\Psi_{JT}$	$\Psi_{JB}$	Unit
CP-28-9	55.09	24.49	19.14	2.62	23.92	°C/W

<sup>&</sup>lt;sup>1</sup> Thermal impedance simulated values are based on a JEDEC 2S2P thermal test board with nine thermal vias. See JEDEC JESD51.

### **ESD CAUTION**



**ESD** (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

# PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

### AD5673R/AD5677R

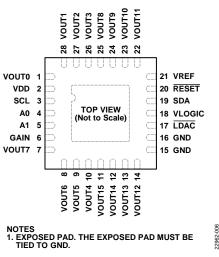


Figure 4. Pin Configuration Diagram

**Table 8. Pin Function Descriptions** 

Table 8.	Pin Function l	Descriptions
Pin No.	Mnemonic	Description
1	VOUT0	Analog Output Voltage from DAC 0. The output amplifier has rail-to-rail operation.
2	VDD	Power Supply Input. These devices operate from 2.7 V to 5.5 V. Decouple the VDD supply with a 10 μF capacitor in
		parallel with a 0.1 μF capacitor to GND.
3	SCL	Serial Clock Line. In conjunction with the SDA line, the SCL pin clocks data into or out of the 24-bit input shift register.
4	A0	Address Input. Sets the first LSB of the 7-bit slave address.
5	A1	Address Input. Sets the second LSB of the 7-bit slave address.
6	GAIN	Span Set. When the GAIN pin is tied to GND, all 16 DAC outputs have a span from 0 V to $V_{REF}$ . If the GAIN pin is tied to VLOGIC, all 16 DACs output a span of 0 V to 2 $\times$ $V_{REF}$ .
7	VOUT7	Analog Output Voltage from DAC 7. The output amplifier has rail-to-rail operation.
8	VOUT6	Analog Output Voltage from DAC 6. The output amplifier has rail-to-rail operation.
9	VOUT5	Analog Output Voltage from DAC 5. The output amplifier has rail-to-rail operation.
10	VOUT4	Analog Output Voltage from DAC 4. The output amplifier has rail-to-rail operation.
11	VOUT15	Analog Output Voltage from DAC 15. The output amplifier has rail-to-rail operation.
12	VOUT14	Analog Output Voltage from DAC 14. The output amplifier has rail-to-rail operation.
13	VOUT13	Analog Output Voltage from DAC 13. The output amplifier has rail-to-rail operation.
14	VOUT12	Analog Output Voltage from DAC 12. The output amplifier has rail-to-rail operation.
15, 16	GND	Ground Reference Point for All Circuitry on the Device.
17	LDAC	Load DAC. LDAC operates in two modes, asynchronously and synchronously. Pulsing Pin 17 low updates any or all
		DAC registers when the input registers have new data, which simultaneously updates all DAC outputs. Pin 17 can also be tied permanently low.
18	VLOGIC	Digital Power Supply. The voltage on Pin 18 is specified in Table 2 and Table 3 within the power requirements parameter section.
19	SDA	Serial Data Input. In conjunction with the SCL line, Pin 19 clocks data into or out of the 24-bit input shift register.  SDA is a bidirectional, open-drain data line that must be pulled to the supply with an external pull-up resistor.
20	RESET	Asynchronous Reset Input. The RESET input is falling edge sensitive. When RESET is low, all LDAC pulses are ignored. When RESET is activated, the input register and the DAC register are updated with zero scale or midscale, depending
		on the model in use.
21	VREF	Reference Output Voltage. When using the internal reference, VREF is the reference output pin. Pin 21 is the reference output by default.
22	VOUT11	Analog Output Voltage from DAC 11. The output amplifier has rail-to-rail operation.
23	VOUT10	Analog Output Voltage from DAC 10. The output amplifier has rail-to-rail operation.
24	VOUT9	Analog Output Voltage from DAC 9. The output amplifier has rail-to-rail operation.
25	VOUT8	Analog Output Voltage from DAC 8. The output amplifier has rail-to-rail operation.

Pin No.	Mnemonic	Description
26	VOUT3	Analog Output Voltage from DAC 3. The output amplifier has rail-to-rail operation.
27	VOUT2	Analog Output Voltage from DAC 2. The output amplifier has rail-to-rail operation.
28	VOUT1	Analog Output Voltage from DAC 1. The output amplifier has rail-to-rail operation.
	EPAD	Exposed Pad. The exposed pad must be tied to GND.

### TYPICAL PERFORMANCE CHARACTERISTICS

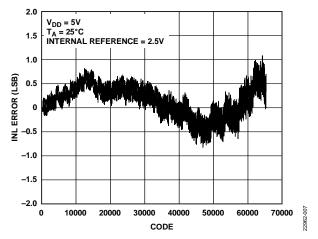


Figure 5. AD5677R INL Error vs. Code

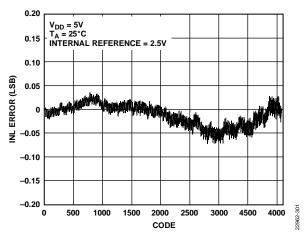


Figure 6. AD5673R INL Error vs. Code

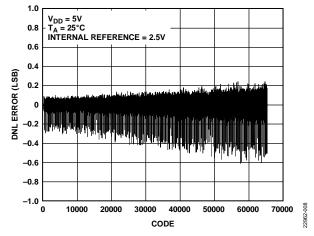


Figure 7. AD5677R DNL Error vs. Code

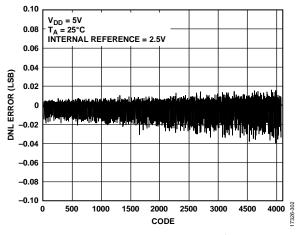


Figure 8. AD5673R DNL Error vs. Code

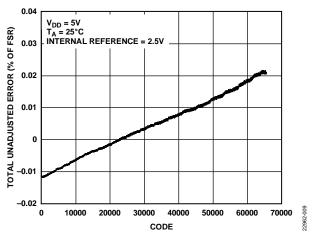


Figure 9. AD5677R Total Unadjusted Error vs. Code

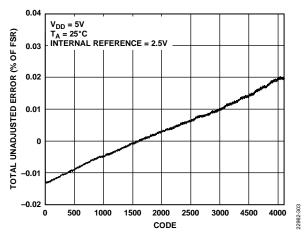


Figure 10. AD5673R Total Unadjusted Error vs. Code

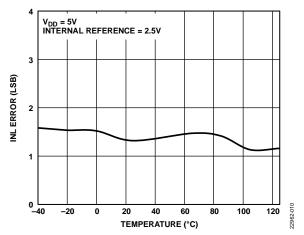


Figure 11. AD5677R INL Error vs. Temperature

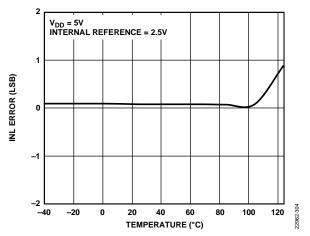


Figure 12. AD5673R INL Error vs. Temperature

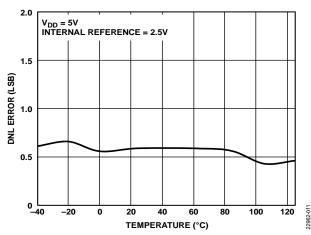


Figure 13. AD5677R DNL Error vs. Temperature

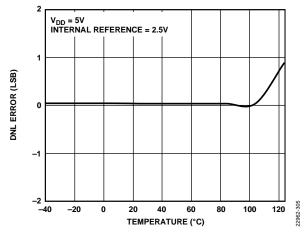


Figure 14. AD5673R DNL Error vs. Temperature

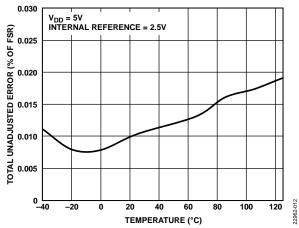


Figure 15. AD5677R Total Unadjusted Error vs. Temperature

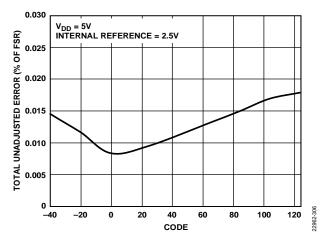


Figure 16. AD5673R Total Unadjusted Error vs. Temperature

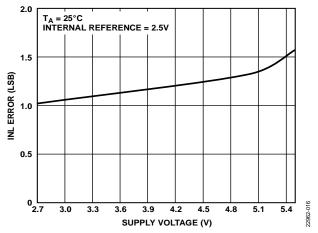


Figure 17. AD5677R INL Error vs. Supply Voltage

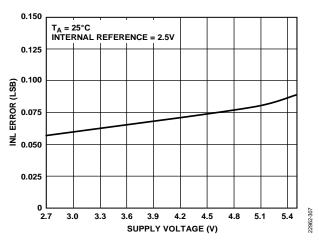


Figure 18. AD5673R INL Error vs. Supply Voltage

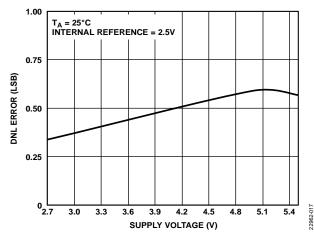


Figure 19. AD5677R DNL Error vs. Supply Voltage

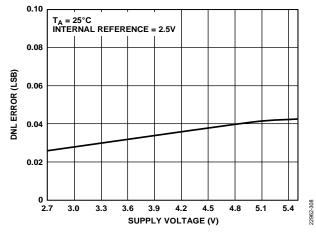


Figure 20. AD5673R DNL Error vs. Supply Voltage

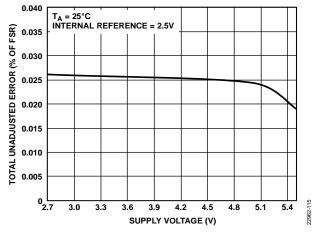


Figure 21. AD5677R Total Unadjusted Error vs. Supply Voltage

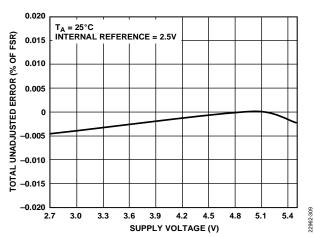


Figure 22. AD5673R Total Unadjusted Error vs. Supply Voltage

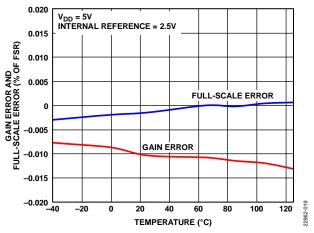


Figure 23. AD5677R Gain Error and Full-Scale Error vs. Temperature

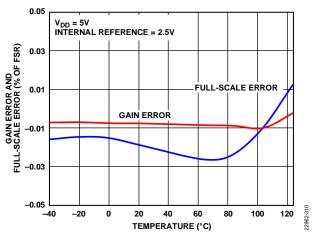


Figure 24. AD5673R Gain Error and Full-Scale Error vs. Temperature

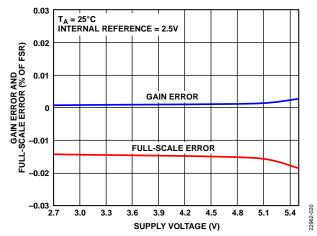


Figure 25. AD5677R Gain Error and Full-Scale Error vs. Supply Voltage

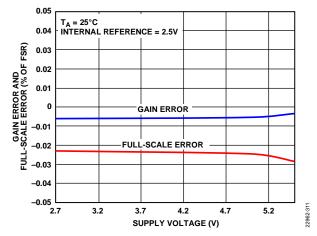


Figure 26. AD5673R Gain Error and Full-Scale Error vs. Supply Voltage

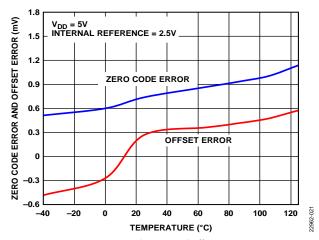


Figure 27. AD5677R Zero Code Error and Offset Error vs. Temperature

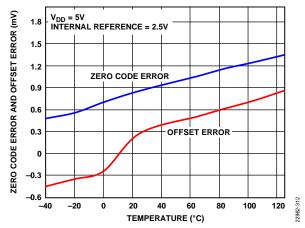


Figure 28. AD5673R Zero Code Error and Offset Error vs. Temperature

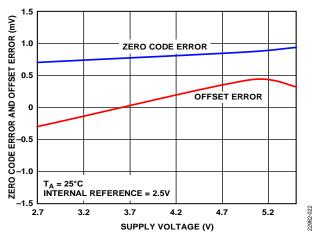


Figure 29. AD5677R Zero Code Error and Offset Error vs. Supply Voltage

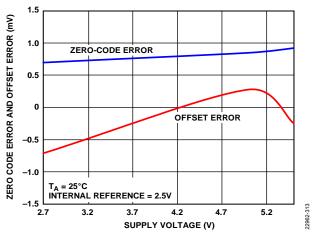


Figure 30. AD5673R Zero Code Error and Offset Error vs. Supply Voltage

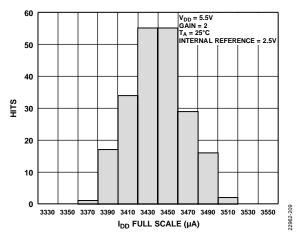


Figure 31. Supply Current (IDD) Histogram with Internal Reference

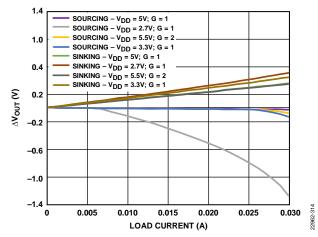


Figure 32. Headroom and Footroom (ΔV<sub>OUT</sub>) vs. Load Current

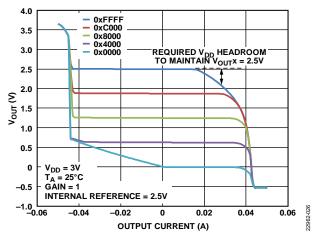


Figure 33. Source and Sink Capability at  $V_{DD} = 3 V$ 

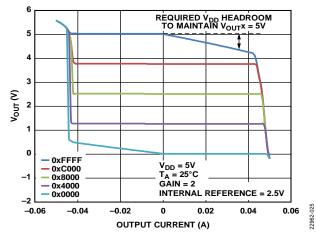


Figure 34. Source and Sink Capability at  $V_{DD} = 5 V$ 

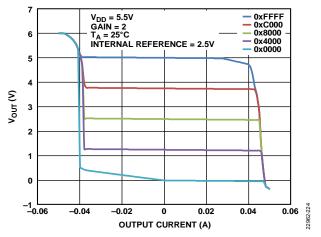


Figure 35. Source and Sink Capability at  $V_{DD} = 5.5 \text{ V}$ 

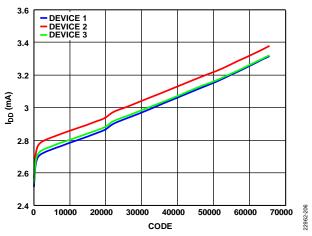


Figure 36. IDD vs. Code

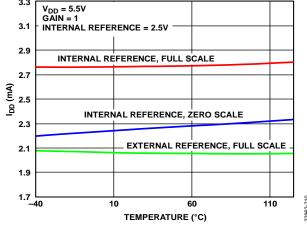


Figure 37. IDD vs. Temperature

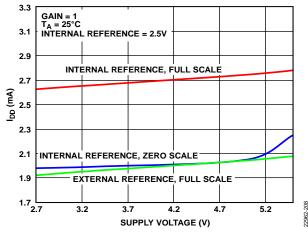


Figure 38. IDD vs. Supply Voltage

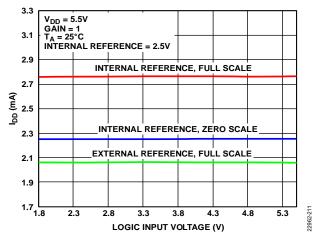


Figure 39. IDD vs. Logic Input Voltage

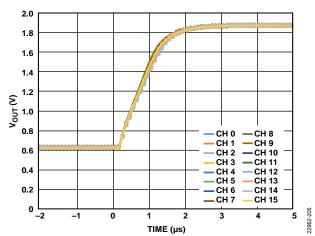


Figure 40. Settling Time

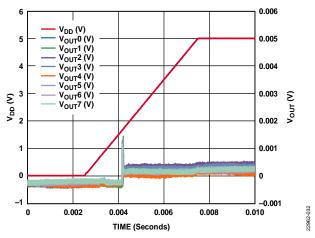


Figure 41. POR to 0 V Output

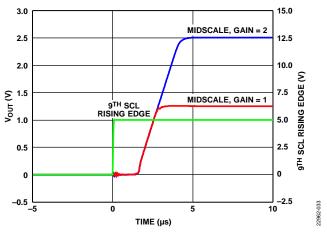


Figure 42. Exiting Power-Down to Midscale

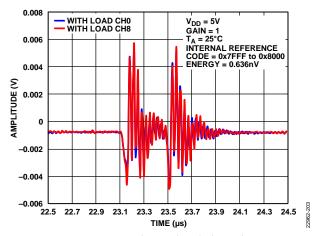


Figure 43. Digital-to-Analog Glitch Impulse

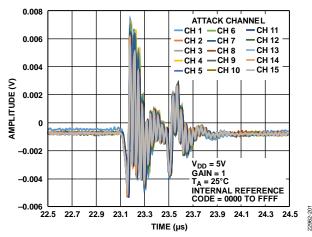


Figure 44. Analog Crosstalk

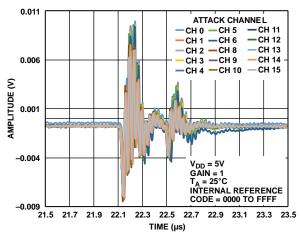


Figure 45. DAC to DAC Crosstalk

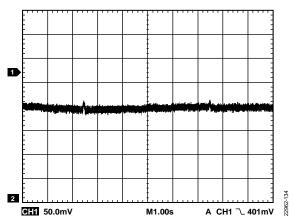
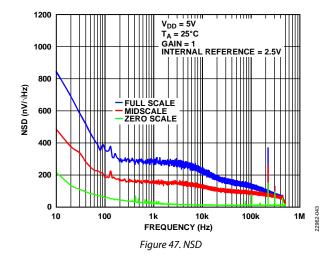
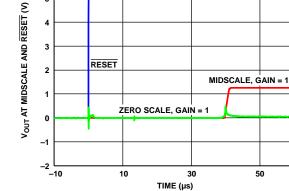


Figure 46. 0.1 Hz to 10 Hz Output Noise

3

1600





RESET



0.30

0.25

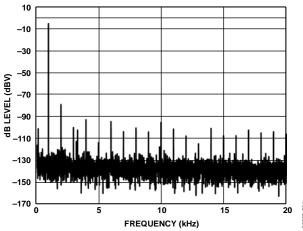
0.20

0.15

-0.05

-0.10

Vout AT 0.05



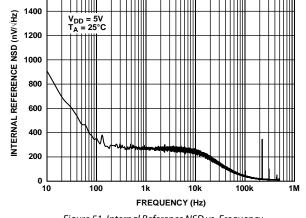
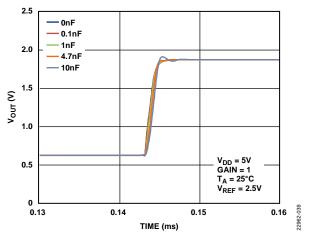


Figure 48. THD at 1 kHz

Figure 51. Internal Reference NSD vs. Frequency



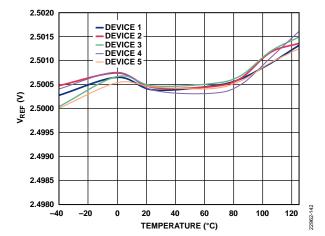
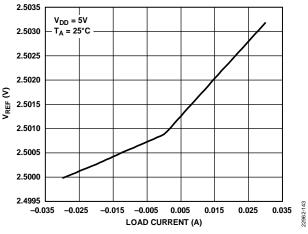
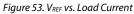


Figure 49. Settling Time at Various Capacitive Loads

Figure 52. V<sub>REF</sub> vs. Temperature





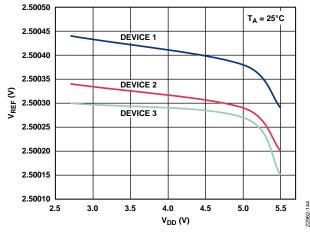


Figure 54. V<sub>REF</sub> vs. V<sub>DD</sub>

### TERMINOLOGY

### Relative Accuracy or Integral Nonlinearity (INL)

For the DAC, relative accuracy or integral nonlinearity is a measurement of the maximum deviation, in LSBs, from a straight line passing through the endpoints of the DAC transfer function.

### Differential Nonlinearity (DNL)

Differential nonlinearity is the difference between the measured change and the ideal 1 LSB change between any two adjacent codes. A specified differential nonlinearity of  $\pm 1$  LSB maximum ensures monotonicity. These DACs are guaranteed monotonic by design.

### **Zero Code Error**

Zero code error is a measurement of the output error when zero code (0x0000) is loaded to the DAC register. The ideal output is 0 V. The zero code error is always positive because the output of the DAC cannot go below 0 V due to a combination of the offset errors in the DAC and the output amplifier. Zero code error is expressed in mV.

### **Full-Scale Error**

Full-scale error is a measurement of the output error when full-scale code (0xFFFF) is loaded to the DAC register. The ideal output is  $V_{\text{REF}}-1$  LSB (gain = 1) or  $2\times V_{\text{REF}}$  (gain = 2). Full-scale error is expressed in percent of full-scale range (% of FSR).

### **Gain Error**

Gain error is a measure of the span error of the DAC. It is the deviation in slope of the DAC transfer characteristic from the ideal expressed as % of FSR.

### Offset Error Drift

Offset error drift is a measurement of the change in offset error with a change in temperature. It is expressed in  $\mu V/^{\circ}C$ .

### **Offset Error**

Offset error is a measure of the difference between  $V_{\text{OUT}}$  (actual) and  $V_{\text{OUT}}$  (ideal) expressed in mV in the linear region of the transfer function. Offset error is measured with Code 256 loaded in the DAC register. It can be negative or positive.

### DC Power Supply Rejection Ratio (PSRR)

The dc power supply rejection ratio indicates how the output of the DAC is affected by changes in the supply voltage. PSRR is the ratio of the change in  $V_{\text{OUT}}x$  to a change in  $V_{\text{DD}}$  for full-scale output of the DAC. It is measured in mV/V.  $V_{\text{REF}}$  is held at 2 V, and  $V_{\text{DD}}$  is varied by  $\pm 10\%$ .

### **Output Voltage Settling Time**

The output voltage settling time is the amount of time it takes for the output of a DAC to settle to a specified level for a ¼ to ¾ full-scale input change.

### Digital-to-Analog Glitch Impulse

Digital-to-analog glitch impulse is the impulse injected into the analog output when the input code in the DAC register changes state. It is normally specified as the area of the glitch in nV-sec, and is measured when the digital input code is changed by 1 LSB at the major carry transition (0x7FFF to 0x8000).

### Digital Feedthrough

Digital feedthrough is a measure of the impulse injected into the analog output of the DAC from the digital inputs of the DAC, but is measured when the DAC output is not updated. It is specified in nV-sec, and measured with a full-scale code change on the data bus, that is, from all 0s to all 1s and vice versa.

### Noise Spectral Density (NSD)

Noise spectral density is a measurement of the internally generated random noise. Random noise is characterized as a spectral density ( $nV/\sqrt{Hz}$ ). It is measured by loading the DAC to midscale and measuring noise at the output. It is measured in  $nV/\sqrt{Hz}$ .

### **DC Crosstalk**

DC crosstalk is the dc change in the output level of one DAC in response to a change in the output of another DAC. It is measured with a full-scale output change on one DAC (or soft power-down and power-up) while monitoring another DAC kept at midscale. It is expressed in  $\mu V$ .

DC crosstalk due to load current change is a measure of the impact that a change in load current on one DAC has on another DAC kept at midscale. It is expressed in  $\mu V/mA$ .

### **Digital Crosstalk**

Digital crosstalk is the glitch impulse transferred to the output of one DAC at midscale in response to a full-scale code change (all 0s to all 1s and vice versa) in the input register of another DAC. It is measured in standalone mode and is expressed in nV-sec.

### **Analog Crosstalk**

Analog crosstalk is the glitch impulse transferred to the output of one DAC due to a change in the output of another DAC. It is measured by first loading one of the input registers with a full-scale code <a href="change">change</a> (all 0s to all 1s and vice versa). Then, execute a software <a href="LDAC">LDAC</a> and monitor the output of the DAC whose digital code was not changed. The area of the glitch is expressed in nV-sec.

### **DAC to DAC Crosstalk**

DAC to DAC crosstalk is the glitch impulse transferred to the output of one DAC due to a digital code change and subsequent analog output change of another DAC. DAC to DAC crosstalk is measured with a full-scale change on one DAC output (all 0s to all 1s and vice versa), using the write to and update commands, while monitoring the other DAC output kept at midscale. The energy of the glitch is expressed in nV-sec.

### **Total Harmonic Distortion (THD)**

THD is the difference between an ideal sine wave and its attenuated version using the DAC. The sine wave is used as the reference for the DAC, and the THD is a measurement of the harmonics present on the DAC output. It is measured in dB.

### **Voltage Reference Temperature Coefficient (TC)**

Voltage reference TC is a measure of the change in the reference output voltage with a change in temperature. The reference TC is calculated using the box method, which defines the TC as the maximum change in the reference output over a given temperature range expressed in ppm/°C, as follows:

$$TC = \left(\frac{V_{REF\_MAX} - V_{REF\_MIN}}{V_{REF\_NOM} \times TEMP\_RANGE}\right) \times 10^{6}$$

where:

 $V_{REF\_MAX}$  is the maximum reference output measured over the total temperature range.

 $V_{REF\_MIN}$  is the minimum reference output measured over the total temperature range.

 $V_{REF\_NOM}$  is the nominal reference output voltage, 2.5 V.  $TEMP\_RANGE$  is the specified temperature range of  $-40^{\circ}$ C to  $+125^{\circ}$ C.

# THEORY OF OPERATION DIGITAL-TO-ANALOG CONVERTER (DAC)

The AD5673R/AD5677R are 16-channel, 12-/16-bit, serial input, voltage output DACs with an internal reference. The devices operate from supply voltages of 2.7 V to 5.5 V. Data is written to the AD5673R/AD5677R in a 24-bit word format via a 2-wire serial interface. The AD5673R/AD5677R incorporate a power-on reset circuit to ensure that the DAC output powers up to a known output state. The devices also have a software power-down mode that reduces the typical current consumption to 2  $\mu A$ .

### TRANSFER FUNCTION

The internal reference is on by default.

The gain of the output amplifier can be set to  $\times 1$  or  $\times 2$  using the span set pin (GAIN). When the GAIN pin is tied to GND, all 16 DAC outputs have a span from 0 V to  $V_{REF}$ . When the GAIN pin is tied to VLOGIC, all 16 DACs output a span of 0 V to  $2 \times V_{REF}$ .

### **DAC ARCHITECTURE**

The AD5673R/AD5677R implement a segmented string DAC architecture with an internal output buffer. Figure 55 shows the internal block diagram.

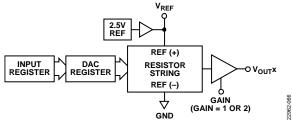


Figure 55. Single DAC Channel Architecture Block Diagram

The resistor string structure is shown in Figure 56.

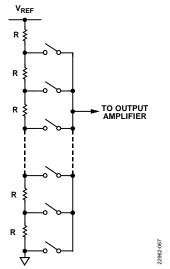


Figure 56. Resistor String Structure

The code loaded to the DAC register determines the node on the string where the voltage is tapped off and fed into the output amplifier. The voltage is tapped off by closing one of the switches and connecting the string to the amplifier. Because each resistance in the string has the same value, R, the string DAC is guaranteed monotonic.

### **Internal Reference**

The AD5673R/AD5677R on-chip reference is enabled at power-up, but the on-chip reference can be disabled via a write to the control register. See the Internal Reference Setup section for details.

The AD5673R/AD5677R have a 2.5 V, 2 ppm/°C reference, giving a full-scale output of 2.5 V or 5 V, depending on the state of the GAIN pin. The internal reference associated with the device is available at the VREF pin. This buffered reference is capable of driving external loads of up to 15 mA.

### **Output Amplifiers**

The output buffer amplifier generates rail-to-rail voltages on its output, which gives an output range of 0 V to  $V_{\rm DD}$ . The actual range depends on the value of the voltage reference level ( $V_{\rm REF}$ ) the GAIN pin, the offset error, and the gain error.

The output amplifiers can drive a load of 1 k $\Omega$  in parallel with 10 nF to GND. The slew rate is 0.8 V/ $\mu$ s with a typical ½ to ¾ scale settling time of 6  $\mu$ s.

### **SERIAL INTERFACE**

The AD5673R/AD5677R use a 2-wire,  $I^2C$ -compatible serial interface. These devices can be connected to an  $I^2C$  bus as a slave device under the control of the master devices. The AD5673R/AD5677R support standard (100 kHz) and fast (400 kHz) data transfer modes. Support is not provided for 10-bit addressing and general call addressing.

### **Input Shift Register**

The input shift register of the AD5673R/AD5677R is 24 bits wide. Data is loaded MSB first (DB23), and the first four bits are the command bits, C3 to C0 (see Table 9), followed by the 4-bit DAC address bits, A3 to A0 (see Table 10), and finally, the 16-bit data-word.

The data-word comprises a 16-bit input code for the AD5677R, and a 12-bit input code followed by four zeros, or don't care bits, for the AD5673R (see Figure 57 and Figure 58). These data bits are transferred to the input register on the 24 falling edges of SCL.

Commands execute on individual DAC channels, combined DAC channels, or on all DACs, depending on the address bits selected.

DB23	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB15	DB14	DB13	DB12	DB11	DB10	DB9	DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
С3	C2	C1	C0	А3	A2	A1	A0	D15	D14	D13	D12	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0
	COMMAND DAC ADDRESS DAC DATA									DAC	DATA												
COMMAND BYTE						D	ATA HI	GH BY	ΓΕ					D	ATA LO	W BYT	Έ						

Figure 57. AD5677R Input Shift Register Content

DB23	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB15	DB14	DB13	DB12	DB11	DB10	DB9	DB8	DB7	DB6	DB5	DB4	DB3	DB2	DB1	DB0
СЗ	C2	C1	CO	А3	A2	A1	A0	D11	D10	D9	D8	D7	D6	D5	D4	D3	D2	D1	D0	Х	Х	х	Х
	COMMAND DAC ADDRESS				3	DAC DATA							DAC DATA										
	COMMAND BYTE							D	ATA HI	GH BY1	E					D	ATA LC	W BYT	Έ				

Figure 58. AD5673R Input Shift Register Content

**Table 9. Command Definitions** 

	Comr	nand		
<b>C</b> 3	C2	<b>C</b> 1	C0	Description
0	0	0	0	No operation
0	0	0	1	$\frac{\text{Write}}{\text{LDAC}} \text{ to Input Register x (dependent on }$
0	0	1	0	Update DAC Register x with contents of Input Register x
0	0	1	1	Write to and update DAC Channel $x$ (Independent of LDAC)
0	1	0	0	Power down/power up the DAC
0	1	0	1	Hardware LDAC mask register
0	1	1	0	Software reset (power-on reset)
0	1	1	1	Internal reference setup register
1	0	0	0	Reserved
1	0	0	1	Set up the readback register (readback enable)
1	0	1	0	Update all channels of the input register simultaneously with the input data
1	0	1	1	Update all channels of the DAC register and input register simultaneously with the input data
1	1	0	0	Reserved
1	1	1	1	Reserved

### Table 10. Address Commands

		ess, Bits		
А3	A2	A1	A0	Selected Channel
0	0	0	0	DAC 0
0	0	0	1	DAC 1
0	0	1	0	DAC 2
0	0	1	1	DAC 3
0	1	0	0	DAC 4
0	1	0	1	DAC 5
0	1	1	0	DAC 6
0	1	1	1	DAC 7
1	0	0	0	DAC 8
1	0	0	1	DAC 9
1	0	1	0	DAC 10
1	0	1	1	DAC 11
1	1	0	0	DAC 12
1	1	0	1	DAC 13
1	1	1	0	DAC 14
1	1	1	1	DAC 15

### WRITE AND UPDATE COMMANDS

### Write to Input Register x (Dependent on LDAC)

Command 0001 allows the user to write the dedicated input register of each DAC individually. When  $\overline{\text{LDAC}}$  is low, the input register is transparent if the transparency is not controlled by the  $\overline{\text{LDAC}}$  mask register.

### Update DAC Register x with Contents of Input Register x

Command 0010 loads the DAC registers with the contents of the input registers selected and updates the DAC outputs directly. Data Bit D15 to Bit D0 determine which DACs have data from the input register transferred to the DAC register. Setting a bit to 1 transfers data from the input register to the appropriate DAC register.

# Write to and Update DAC Channel x (Independent of LDAC)

Command 0011 allows the user to write to the DAC registers and updates the DAC outputs directly. The DAC address bits select the DAC channel.

### I<sup>2</sup>C SLAVE ADDRESS

The AD5673R/AD5677R have a 7-bit I<sup>2</sup>C slave address. The five MSBs are 00011, and the two LSBs (A1 and A0) are set by the state of the A1 and A0 address pins. The ability to make hardwired changes to A1 and A0 allows the user to incorporate up to four AD5673R or AD5677R devices on one bus (see Table 11).

**Table 11. Device Address Selection** 

A1 Pin Connection	A0 Pin Connection	A1	A0
GND	GND	0	0
GND	VLOGIC	0	1
VLOGIC	GND	1	0
VLOGIC	VLOGIC	1	1

### **SERIAL OPERATION**

The 2-wire I<sup>2</sup>C serial bus protocol operates as follows:

- The master initiates a data transfer by establishing a start condition when a high to low transition on the SDA line occurs while SCL is high. The following byte is the address byte, which consists of the 7-bit slave address.
- The slave device with the transmitted address responds by pulling SDA low during the ninth clock pulse (this is called the acknowledge bit, or ACK). At this stage, all other devices on the bus remain idle while the selected device waits for data to be written to or read from its input shift register.
- Data is transmitted over the serial bus in sequences of nine clock pulses (eight data bits followed by an acknowledge bit).
   Transitions on the SDA line must occur during the low period of SCL. SDA must remain stable during the high period of SCL.
- After all data bits are read or written, a stop condition is established. In write mode, the master pulls the SDA line high during the 10<sup>th</sup> clock pulse to establish a stop condition. In read mode, the master issues a no acknowledge (NACK)

for the ninth clock pulse (that is, the SDA line remains high). The master then brings the SDA line low before the  $10^{\rm th}$  clock pulse, and then high again during the  $10^{\rm th}$  clock pulse to establish a stop condition.

### **WRITE OPERATION**

When writing to the AD5673R/AD5677R, begin with a start command followed by an address byte  $(R/\overline{W}=0)$ , after which the DAC acknowledges that it is prepared to receive data by pulling SDA low. The AD5673R/AD5677R require two bytes of data for the DAC and a command byte to control various DAC functions. Three bytes of data must therefore be written to the DAC with the command byte followed by the most significant data byte and the least significant data byte, as shown in Figure 59. All these data bytes are acknowledged by the AD5673R/AD5677R. A stop condition follows.

### **READ OPERATION**

When reading data back from the AD5673R/AD5677R, begin with a start command followed by an address byte ( $R/\overline{W}=0$ ), after which the DAC acknowledges that it is prepared to receive data by pulling SDA low. The address byte must be followed by the command byte, which determines both the read command (0x9) that is to follow and the pointer address to read from. The command byte is also acknowledged by the DAC. The user configures the channel to read back the contents of one or more DAC input registers and, using the command byte, sets the readback command to active. The command byte must be followed by two dummy bytes of data.

Then, the master establishes a repeated start condition, and the address is resent with  $R/\overline{W}=1$ . This byte is acknowledged by the DAC, indicating that it is prepared to transmit data. Two bytes of data are then read from the DAC, as shown in Figure 60. A no acknowledge condition from the master, followed by a stop condition, completes the read sequence. If more than one DAC is selected, DAC 0 is read back by default.

### **MULTIPLE DAC READBACK SEQUENCE**

When reading data back from multiple AD5673R/AD5677R DACs, the user begins with an address byte  $(R/\overline{W}=0)$ , after which the DAC acknowledges that it is prepared to receive data by pulling SDA low. The address byte must be followed by the command byte. The command byte, which determines both the read command (0x9) that is to follow and the pointer address to read from, is also acknowledged by the DAC. The user selects the first channel to read back using the command byte. The command byte must be followed by two dummy bytes of data.

Following this sequence, the master establishes a repeated start condition, and the address is resent with  $R/\overline{W}=1$ . This byte is acknowledged by the DAC, indicating that it is prepared to transmit data. The first two bytes of data are then read from DAC Input Register x (selected using the command byte), MSB first, as shown in Figure 60.

The next two bytes read back are the contents of DAC Input Register x + 1, and the next bytes read back are the contents of DAC Input Register x + 2. Data is read from the DAC input registers in this auto-incremented fashion until a no

acknowledge followed by a stop condition follows. If the contents of DAC Input Register 15 are read out, the next two bytes of data read are the contents of DAC Input Register 0.

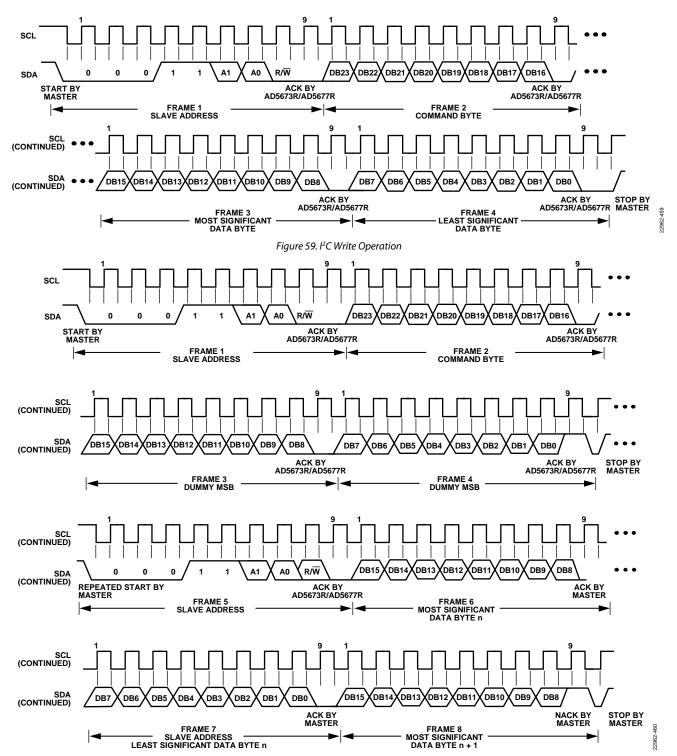


Figure 60. I<sup>2</sup>C Read Operation

### **POWER-DOWN OPERATION**

Command 0100 is designated for the power-down function (see Table 9). These power-down modes are software programmable by setting 16 bits, Bit DB15 to Bit DB0, in the input shift register. Two bits are associated with each DAC channel (PD0 and PD1). Table 12 shows how the state of the two bits corresponds to the mode of operation of the device.

Any or all DACs (DAC 0 to DAC 15) power down to the selected mode by setting the corresponding bits. See Table 13 and Table 14 for the contents of the input shift register during the power-down/power-up operation.

**Table 12. Modes of Operation** 

PD1	PD0	Operating Mode
0	0	Normal operation
0	1	Power-down mode: 1 $k\Omega$ to GND

When both Bit PD1 and Bit PD0 in the input shift register are set to 0, the device works normally with its normal power consumption of typically 2.3 mA at 5 V. However, for the 1 k $\Omega$  to GND power-down mode, the supply current decreases to typically 2  $\mu$ A. In addition to this decrease, the output stage switches internally from the amplifier output to a resistor network of known value. Therefore, the DAC channel output impedance is defined when the channel is powered down by internally connecting the output to GND through a 1 k $\Omega$  resistor. The output stage is shown in Figure 61.

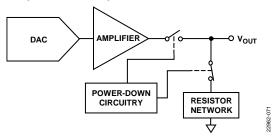


Figure 61. Output Stage During Power-Down

The bias generator, output amplifier, resistor string, and other associated linear circuitry are shut down when power-down mode is activated. However, the contents of the DAC registers are unaffected in power-down mode, and the DAC registers can be updated while the device is in power-down mode. The time required to exit power-down is typically 3  $\mu s$  for  $V_{\rm DD}=5$  V.

To reduce the current consumption further, power off the on-chip reference. See the Internal Reference Setup section.

### **LOAD DAC (HARDWARE LDAC PIN)**

The AD5673R/AD5677R DACs have double buffered interfaces consisting of two banks of registers: input registers and DAC registers. The user can write to any combination of the input registers. Updates to the DAC registers are controlled by the  $\overline{\text{LDAC}}$  pin.

### Instantaneous DAC Updating (LDAC Held Low)

For instantaneous updating of the DACs,  $\overline{\text{LDAC}}$  is held low while data is clocked into the input register using Command 0001. Both the addressed input register and the DAC register are updated on the 24<sup>th</sup> clock, and the output changes immediately.

### Deferred DAC Updating (LDAC is Pulsed Low)

For deferred updating of the DACs,  $\overline{\text{LDAC}}$  is held high while data is clocked into the input register using Command 0001. All DAC outputs are asynchronously updated by pulling  $\overline{\text{LDAC}}$  low after the 24<sup>th</sup> clock. The update occurs on the falling edge of  $\overline{\text{LDAC}}$ .

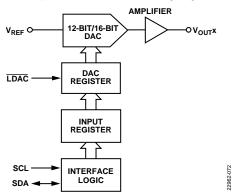


Figure 62. Simplified Diagram of Input Loading Circuitry for a Single DAC

Table 13. 24-Bit Input Shift Register Contents of Power-Down/Power-Up Operation for DAC 7 to DAC 0 Output Channels

			DAC 7	DAC 6	DAC 5	DAC 4	DAC 3	DAC 2	DAC 1	DAC 0
[DB23:DB20]	DB19	[DB18:DB16]	[DB15: B14]	[DB13:B12]	[DB11:B10]	[DB9:DB8]	[DB7:DB6]	[DB5:DB4]	[DB3:DB2]	[DB1:DB0]
0100	0	XXX <sup>1</sup>	[PD1:PD0]	[PD1:PD0]	[PD1:PD0]	[PD1:PD0]	[PD1:PD0]	[PD1:PD0]	[PD1:PD0]	[PD1:PD0]

<sup>&</sup>lt;sup>1</sup> X means don't care.

Table 14. 24-Bit Input Shift Register Contents of Power-Down/Power-Up Operation for DAC 15 to DAC 8 Output Channels

			DAC 15	DAC 14	DAC 13	DAC 12	DAC 11	DAC 10	DAC 9	DAC 8
[DB23:DB20]	DB19	[DB18:DB16]	[DB15: B14]	[DB13:B12]	[DB11:B10]	[DB9:DB8]	[DB7:DB6]	[DB5:DB4]	[DB3:DB2]	[DB1:DB0]
0100	1	XXX <sup>1</sup>	[PD1:PD0]	[PD1:PD0]	[PD1:PD0]	[PD1:PD0]	[PD1:PD0]	[PD1:PD0]	[PD1:PD0]	[PD1:PD0]

<sup>&</sup>lt;sup>1</sup> X means don't care.

### **LDAC MASK REGISTER**

Command 0101 is reserved for the hardware  $\overline{LDAC}$  function. The address bits are ignored. Writing to the DAC using Command 0101 loads the 16-bit  $\overline{LDAC}$  register (DB15 to DB0). The default for each channel is 0, that is, the  $\overline{LDAC}$  pin works normally. Setting DB15 to DB0 to 1 forces this DAC channel to ignore transitions on the  $\overline{LDAC}$  pin, regardless of the state of the hardware  $\overline{LDAC}$  pin. This flexibility is useful in applications where the user wants to select which channels respond to the  $\overline{LDAC}$  pin.

The  $\overline{LDAC}$  register gives the user extra flexibility and control over the hardware  $\overline{LDAC}$  pin (see Table 17). Setting the  $\overline{LDAC}$  bits (DB0 to DB15) to 0 for a DAC channel means that this channel update is controlled by the hardware  $\overline{LDAC}$  pin.

### HARDWARE RESET (RESET)

The RESET pin is an active low reset that allows the outputs to be cleared to either zero scale or midscale. The clear code value depends on the model in use and refers to the power-up voltage. It is necessary to keep the RESET pin low for a minimum time (see Table 5) to complete the operation. When the RESET signal is returned high, the output remains at the cleared value until a new value is programmed. While the RESET pin is low, the outputs cannot be updated with a new value. Any events on LDAC or RESET during power-on reset are ignored. If the RESET pin is pulled low at power-up, the device does not initialize correctly until the pin is released.

### **POWER-ON RESET INTERNAL CIRCUIT**

The AD5673R/AD5677R contain a power-on reset circuit that controls the output voltage during power-up. Depending on the model selected, the output powers up to zero scale (AD5673R-1, AD5677R-1) or the output powers up to midscale (AD5673R-2, AD5677R-2). The output remains powered up at this level until a valid write sequence is made to the DAC.

### **SOFTWARE RESET**

A software executable reset function is also available, which resets the DAC to the power-on reset code. Command 0110 is designated for this software reset function. The DAC address bits must be set to 0x0 and the data bits set to 0x1234 for the software reset command to execute.

### **INTERNAL REFERENCE SETUP**

The on-chip reference is on at power-up by default. To reduce the supply current, turn off this reference by setting the software programmable bit, DB0, in the internal reference setup register.

Table 15 shows how the state of the bit corresponds to the mode of operation. Command 0111 is reserved for setting up the internal reference (see Table 9 and Table 18).

Table 15. Internal Reference Setup Register

Bit	Description
DB2	Reserved
DB1	Reserved; set to 0
DB0	Reference enable
	DB0 = 0; internal reference enabled (default)
	DB0 = 1; internal reference disabled

Table 16. LDAC Overwrite Definition

Load LDAC Regi	ster	
LDAC Bits (DB15 to DB0)	LDAC Pin	LDAC Operation
000000000000000	1 or 0	Determined by the LDAC pin.
111111111111111	X (don't care)	DAC channels update and override the $\overline{\text{LDAC}}$ pin. DAC channels see $\overline{\text{LDAC}}$ as 1.

Table 17. Write Commands and LDAC Pin Truth Table<sup>1</sup>

Command	Description	Hardware LDAC Pin State	Input Register Contents	DAC Register Contents
0001	Write to Input Register x	VLOGIC	Data update	No change (no update)
	(dependent on LDAC)	GND <sup>2</sup>	Data update	Data update
0010	Update DAC Register x with	VLOGIC	No change	Updated with input register contents
	contents of Input Register x	GND	No change	Updated with input register contents
0011	Write to and update DAC	VLOGIC	Data update	Data update
	Channel x	GND	Data update	Data update

<sup>&</sup>lt;sup>1</sup> A high to low hardware LDAC pin transition always updates the contents of the contents of the DAC register with the contents of the input register on channels that are not masked (blocked) by the LDAC mask register.

Table 18. 24-Bit Input Shift Register Contents for Internal Reference Setup Command<sup>1</sup>

			0					1			
DB23 (MSB)	DB22	DB21	DB20	DB19	DB18	DB17	DB16	DB1 to DB3	DB2	DB1	DB0 (LSB)
0	1	1	1	Χ	Χ	Χ	Χ	Х	0	0	1/0
Command bits (C3 to C0)				Address bits (A3 to A0)				Don't care	Reserved	Reserved	Reference setup register

<sup>1</sup> X means don't care.

<sup>&</sup>lt;sup>2</sup> When LDAC is permanently tied low, the LDAC mask bits are ignored.

### **SOLDER HEAT REFLOW**

As with all IC reference voltage circuits, the reference value experiences a shift induced by the soldering process. Analog Devices, Inc., performs a reliability test called precondition to mimic the effect of soldering a device to a board. The output voltage specification in Table 2 and Table 3 includes the effect of this reliability test.

Figure 63 shows the effect of solder heat reflow as measured through the reliability test (precondition).

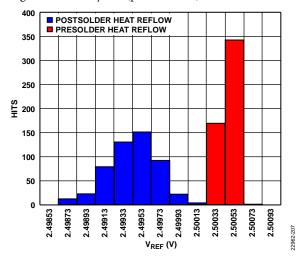


Figure 63. Solder Heat Reflow Reference Voltage Shift

### LONG-TERM TEMPERATURE DRIFT

Figure 64 shows the change in  $V_{\text{REF}}$  value after 1000 hours in the life test at 150°C.

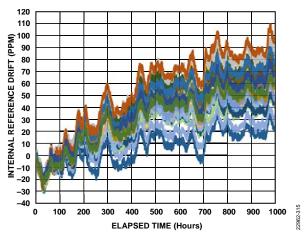


Figure 64. Reference Drift Through to 1000 Hours

### THERMAL HYSTERESIS

Thermal hysteresis is the voltage difference induced on the reference voltage by sweeping the temperature from ambient to cold, to hot, and then back to ambient.

Thermal hysteresis data is shown in Figure 65. Thermal hysteresis is measured by sweeping the temperature from ambient to  $-40^{\circ}$ C, then to  $+125^{\circ}$ C, and returning to ambient.  $\Delta V_{REF}$  is then measured between the two ambient measurements, as shown in Figure 65 (first temperature sweep).

The same temperature sweep and measurements were immediately repeated, and the results are shown in Figure 65 (subsequent temperature sweeps).

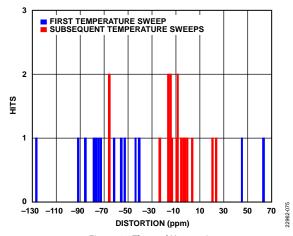


Figure 65. Thermal Hysteresis

# APPLICATIONS INFORMATION POWER SUPPLY RECOMMENDATIONS

The AD5673R/AD5677R are typically powered by the following supplies:  $V_{DD} = 3.3 \text{ V}$  and  $V_{LOGIC} = 1.8 \text{ V}$ .

The ADP118 can be used to power the VDD pin. The ADP160 can be used to power the VLOGIC pin. Figure 66 shows this setup. The ADP118 can operate from input voltages up to 20 V. The ADP160 can operate from input voltages up to 5.5 V.



Figure 66. Low Noise Power Solution for the AD5673R/AD5677R

### MICROPROCESSOR INTERFACING

Microprocessor interfacing to the AD5673R/AD5677R uses a serial bus with a standard protocol that is compatible with DSP processors and microcontrollers. The communications channel requires a 2-wire interface consisting of a clock signal and a data signal.

### AD5673R/AD5677R TO ADSP-BF531 INTERFACE

The I<sup>2</sup>C interface of the AD5673R/AD5677R is designed for easy connection to industry-standard DSPs and microcontrollers. Figure 67 shows the AD5673R/AD5677R connected to the Analog Devices, Inc., ADSP-BF531 Blackfin® processor. The Blackfin processor has an integrated I<sup>2</sup>C port that can be connected directly to the I<sup>2</sup>C pins of the AD5673R/AD5677R.

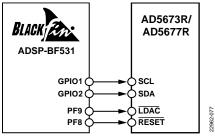


Figure 67. AD5673R/AD5677R to ADSP-BF531 Interface

### **LAYOUT GUIDELINES**

In any circuit where accuracy is important, careful consideration of the power supply and ground return layout helps to ensure the rated performance. Design the PCB on which the AD5673R or AD5677R is mounted so that the device lies on the analog plane.

The AD5673R/AD5677R must have ample supply bypassing of 10  $\mu F$  in parallel with 0.1  $\mu F$  on each supply, located as close to the package as possible, ideally right up against the device. The 10  $\mu F$  capacitors are tantalum bead type. The 0.1  $\mu F$  capacitor

must have low effective series resistance (ESR) and low effective series inductance (ESI), such as the common ceramic types, which provide a low impedance path to ground at high frequencies to handle transient currents due to internal logic switching.

In systems where there are many devices on one board, it is often useful to provide some heat sinking capability to allow the power to dissipate easily.

The GND plane on the device can be increased (as shown in Figure 68) to provide a natural heat sinking effect.

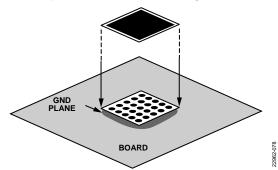


Figure 68. Pad Connection to Board

### **GALVANICALLY ISOLATED INTERFACE**

In many process control applications, it is necessary to provide an isolation barrier between the controller and the unit being controlled to protect and isolate the controlling circuitry from any hazardous common-mode voltages that may occur. *i*Coupler\* products from Analog Devices provide voltage isolation in excess of 2.5 kV. The serial loading structure of the AD5673R/AD5677R makes the devices ideal for isolated interfaces because the number of interface lines is kept to a minimum. Figure 69 shows a 2-channel isolated interface to the AD5673R/AD5677R using an ADuM1251. For further information, visit www.analog.com/icoupler.

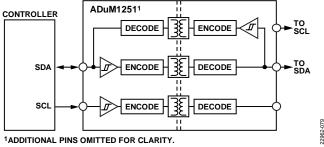


Figure 69. Isolated Interface

### **OUTLINE DIMENSIONS**

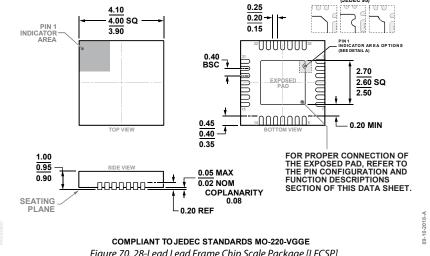


Figure 70. 28-Lead Lead Frame Chip Scale Package [LFCSP] 4 mm × 4 mm Body and 0.95 mm Package Height (CP-28-9) Dimensions shown in millimeters

### **ORDERING GUIDE**

Model <sup>1, 2</sup>	Resolution	Temperature Range	Reset Value	Package Description	Package Option
AD5673RBCPZ-1	12 Bits	-40°C to +125°C	Zero scale	28-Lead LFCSP	CP-28-9
AD5673RBCPZ-1-RL7	12 Bits	-40°C to +125°C	Zero scale	28-Lead LFCSP	CP-28-9
AD5673RBCPZ-2	12 Bits	-40°C to +125°C	Midscale	28-Lead LFCSP	CP-28-9
AD5673RBCPZ-2-RL7	12 Bits	−40°C to +125°C	Midscale	28-Lead LFCSP	CP-28-9
AD5677RBCPZ-1	16 Bits	-40°C to +125°C	Zero scale	28-Lead LFCSP	CP-28-9
AD5677RBCPZ-1-RL7	16 Bits	-40°C to +125°C	Zero scale	28-Lead LFCSP	CP-28-9
AD5677RBCPZ-2	16 Bits	-40°C to +125°C	Midscale	28-Lead LFCSP	CP-28-9
AD5677RBCPZ-2-RL7	16 Bits	-40°C to +125°C	Midscale	28-Lead LFCSP	CP-28-9
EVAL-AD5677RSDZ				AD5677R Evaluation Board	

 $<sup>^{1}</sup>$  Z = RoHS Compliant Part.

 $I^2 C\ refers\ to\ a\ communications\ protocol\ originally\ developed\ by\ Philips\ Semiconductors\ (now\ NXP\ Semiconductors).$ 



<sup>&</sup>lt;sup>2</sup> Use the EVAL-AD5677RSDZ to evaluate the AD5673R models.

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## Analog Devices Inc.:

<u>AD5673RBCPZ-1</u> <u>AD5673RBCPZ-1-RL7</u> <u>AD5677RBCPZ-1</u> <u>AD5677RBCPZ-1-RL7</u> <u>AD5677RBCPZ-2-RL7</u> <u>AD5673RBCPZ-2-RL7</u> <u>AD5677RBCPZ-1-RL7</u> <u>AD5677RBCPZ-1</u>